

ACS108-5Sx

ASDTM AC Switch Family

AC LINE SWITCH

MAIN APPLICATIONS

- . AC Line switch for appliance control systems
- Drive of low power high inductive or resistive loads like:
 - solenoid, relay, valve, dispenser
 - micro-motor
 - door lock
 - low power lamp bulb
 - pump
 - fan

FEATURES

- $_{1}$ V_{DRM} / $V_{RRM} = 500V$
- Avalanche controlled device
- $I_{T(RMS)} = 0.8 A$
- . Gate triggering current : I_{GT} < 10 mA
- Switch integrated driver
- Drive reference COM connected to the SOT223 tab

BENEFITS

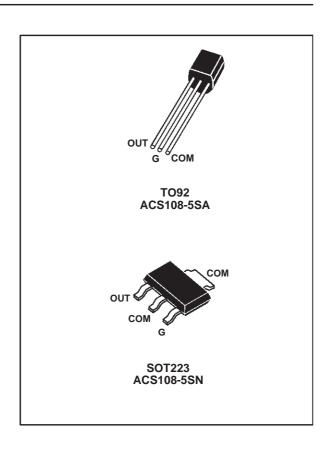
- Needs no more external protection snubber & varistor.
- Enables the equipment to meet IEC1000-4-5 standard.
- Allows straightforward connection of several SOT223 devices on the same cooling pad.
- Reduces the switch component count by up to 80%.
- . Interfaces directly with the microcontroller.
- Eliminates any stressing gate kick back on the microcontroller.

DESCRIPTION

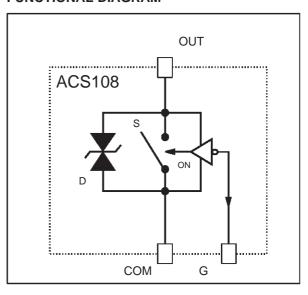
The ACS108 belongs to the AC line switches built around the ASD™ concept. This high performance full planar technology device is able to control an 0.8 A load.

The ACS™ switch embeds a high voltage clamping structure to absorb the inductive turn-off energy and a gate level shifter driver to separate the digital controller from the main switch. It is triggered with a negative gate current flowing out of the gate pin.

Note: For further technical information, please refer to the Application note AN1172.



FUNCTIONAL DIAGRAM



November 1999 - Ed: 3B 1/7

ACS108-5Sx

ABSOLUTE RATINGS (limiting values)

Symbol	Paramete	Value	Unit		
V _{DRM} V _{RRM}	Repetitive peak off-state voltage	Tj = 25 °C	500	V	
I _{T(RMS)}	RMS on-state current full cycle sine	TO92	Tlead = 60 °C	0.8	Α
	wave 50 to 60 Hz	TO92	Tamb = 60 °C	0.3	Α
		SOT223	Tamb = 55 °C	0.8	Α
I _{TSM}	Non repetitive surge peak on-state curre	F =50 Hz	7.3	Α	
	Tj initial = 25⊃C, full cycle sine wave		F =60 Hz	8	Α
dl/dt	Critical rate of rise of on-state current I _G = 20mA with tr = 100ns	Repetitive F =120 Hz	20	A/μs	
V_{PP}	Non repetitive line peak pulse voltage note 1			2	kV
Tstg	Storage temperature range			- 40 to + 150	°C
Tj	Operating junction temperature range			0 to + 110	°C
TI	Maximum lead temperature for soldering during 10s			260	°C

note 1 : according to test described by IEC 1000-4-5 standard & Figure 3.

SWITCH GATE CHARACTERISTICS (maximum values)

Symbol	Parameter	Value	Unit
P _{G (AV)}	Average gate power dissipation	0.1	W
I _{GM}	Peak gate current (tp = 20 _μ s)	1	Α
V _{GM}	Peak positive gate voltage (respect to the pin COM)	5	V

THERMAL RESISTANCES

Symbol	Parameter	Value	Unit	
Rth (j-a)	Junction to ambient TO92		150	°C/W
		SOT223 (*)	60	°C/W
Rth (j-l)	Junction to lead for full AC line cycle conduction	TO92	60	°C/W
Rth (j-t)	Junction to tab for full AC line cycle conduction	SOT223	25	°C/W

^{(*):} with 5cm² copper (e=35μm) surface under tab

ELECTRICAL CHARACTERISTICS

For either positive or negative polarity of pin OUT voltage respect to pin COM voltage

Symbol	Test Conditions			Values	Unit
I _{GT}	V_{OUT} =12 V (DC) R_L =140 Ω	Tj=25°C	MAX	10	mA
V_{GT}	V_{OUT} =12 V (DC) R_L =140 Ω	Tj=25°C	MAX	1	V
V_{GD}	$V_{OUT}=V_{DRM}$ $R_L=3.3k\Omega$	Tj=110°C	MIN	0.2	V
I _H	I _{OUT} = 100mA gate open	Tj=25°C	TYP	25	mA
			MAX	60	mA
IL	I _G = 20mA	Tj=25°C	TYP	30	mA
			MAX	65	mA
V _{TM}	IOUT = 1.1A tp=380μs	Tj=25°C	MAX	1.3	V
I _{DRM}	$V_{OUT} = V_{DRM}$	Tj=25°C	MAX	2	μΑ
I _{RRM}	V _{OUT} = V _{RRM}	Tj=110°C	MAX	50	μΑ
dV/dt	V _{OUT} =400V gate open	Tj=110°C	MIN	500	V/μs
(dl/dt)c	(dV _{OUT} /dt)c=10V/μs	Tj=110°C	MIN	0.1	A/ms
V _{CL}	ICL = 1mA tp=1ms	Tj=25°C	TYP	600	V

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AC LINE SWITCH BASIC APPLICATION

The ACS108 device is well adapted to washing machine, dishwasher, tumble drier, refrigerator, water heater and cookware. It has been designed especially to switch ON and OFF low power loads such as solenoid, valve, relay, micro-motor, fan, pump, door lock and low wattage lamp bulb.

Pin COM: Common drive reference to connect to the power line neutral

Pin G: Switch Gate input to connect to the digital controller

Pin OUT: Switch Output to connect to the Load

The ACSTM switch is triggered with a negative gate current flowing out of the gate pin G. It can be driven directly by the digital controller through a resistor as shown on the typical application diagram. Note that no protection device (zener or capacitor) should be added between gates and common terminals.

The SOT223 version allows several ACS108 devices to be connected on the same cooling PCB pad which is the COM pin: this cooling pad can be then reduced, and the printed circuit layout is simplified. In appliances systems, the ACS108 switch intends to drive low power load in full cycle ON / OFF mode. When the gate signal is removed, the load is switched off after a delay time that is equal to one half line cycle or one full line cycle depending on the load drive strategy.

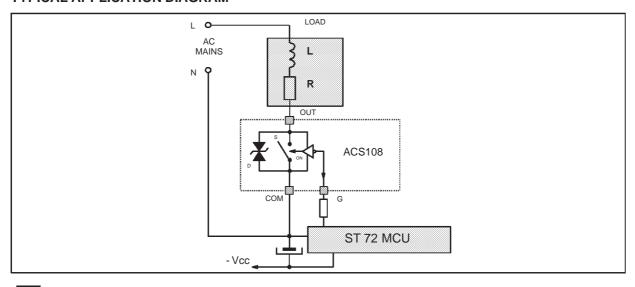
The turn off commutation characteristics of these loads can be classified in 3 groups as shown in table 1.

Thanks to its thermal and turn off commutation performances, the ACS108 switch is able to drive with no additional turn off snubber, a resistive or inductive load up to 0.2 A (when this load has to switch off within one half AC line cycle), an inductive load up to 0.6 A or a resistive load up to 0.8 A (when this load has to switch off within one full AC line cycle).

Table 1: Load grouping versus their turn off commutation requirement (230V AC applications).

LOAD	IRMS (A)	POWER FACTOR	(dl/dt)c (A/ms)	(dV/dt)c (V/μs)	TURN-FF DELAY (ms)
Door Lock Lamp	< 0.3	1	0.15	0.15	<10
	< 0.8	1	0.4	0.15	< 20
Relay Valve Dispenser Micro-motor	< 0.1	> 0.7	< 0.05	< 5	< 10
Pump Fan	< 0.2	> 0.2	< 0.1	< 10	< 10
	< 0.6	> 0.2	< 0.3	< 10	< 20

TYPICAL APPLICATION DIAGRAM



INDUCTIVE SWITCH-OFF OPERATION

At the end of the last conduction half-cycle, the load current reaches the holding current level I_H , and the ACSTM switch turns off. Because of the inductance L of the load, the current flows through the avalanche diode D and decreases linearly to zero. During this time, the voltage across the switch is limited to the clamping voltage V_{CL} .

The energy stored in the inductance of the load depends on the holding current I_H and the inductance (up to 10 H); it can reach about 20 mJ and is dissipated in the clamping section that is especially designed for that purpose.

Fig 1: Turn-off operation of the ACS108 switch with an electro valve: waveform of the gate current I_{G} , pin OUT current I_{OUT} & voltage V_{OUT} .

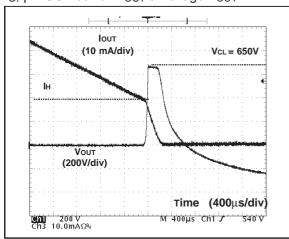
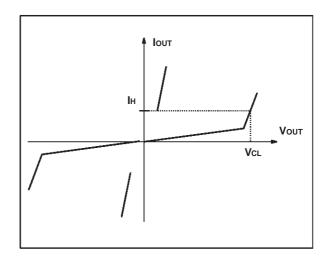


Fig 2: ACS108 switch static characteristic.



AC LINE TRANSIENT VOLTAGE RUGGEDNESS

The ACS108 switch is able to sustain safely the AC line transient voltages either by clamping the low energy spikes or by breaking over under high energy shocks, even with high turn-on current rises.

The test circuit of the figure 4 is representative of the final ACSTM application and is also used to stress the ACSTM switch according to the IEC1000-4-5 standard conditions. Thanks to the load, the ACSTM switch sustains the voltage spikes up to $2 \, \text{kV}$ above the peak line voltage. It will break over safely even on resistive load where the turn on current rise is high as shown on figure 4. Such non repetitive test can be done 10 times on each AC line voltage polarity.

Fig 3: Overvoltage ruggedness test circuit for resistive and inductive loads according to IEC 1000-4-5 standard.

 $R = 150\Omega$, $L = 5\mu H$, $V_{PP} = 2kV$.

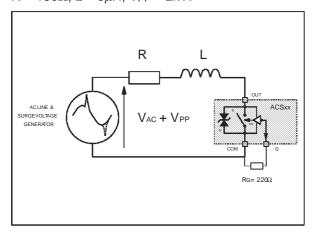
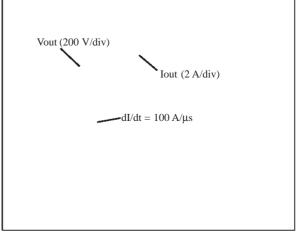


Fig 4: Current and voltage of the ACSTM during IEC 1000-4-5 standard test with a 220Ω - 10μH load & V_{PP} = 2kV.



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Fig 5: Relative variation of gate trigger current versus junction temperature

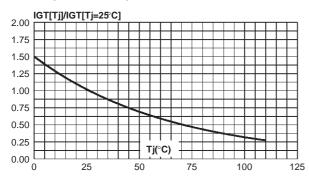


Fig 7: On state characteristics @Tj max $V_{TO} = 0.90 \, V_{\Delta} \, R_{T} = 0.3 \, \Omega \, (maximum \, values)$ Pon = $V_{TO} \cdot 2. \, \sqrt{2} \cdot I_{T(RMS)} / \Pi + R_{T} \, x \, I_{T(RMS)}^{2}$

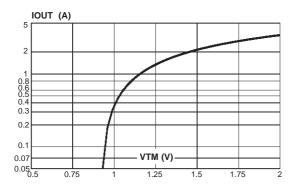


Fig 9-1: Relative variation of the junction to ambient thermal impedance versus conducting pulse duration for the SOT223 Standard foot print with $35\mu m$ copper layout thickness.

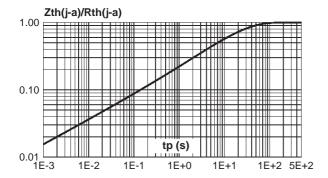


Fig 6: Relative variation of holding & latching currents versus junction temperature

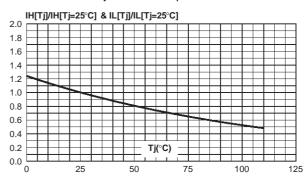


Fig 8: Maximum RMS switch current versus ambient temperature on inductive load (PF>0.1) and a low repetitive rate (F < 1 Hz) (*): with 5cm^2 copper (e= $35\mu\text{m}$) surface under tab

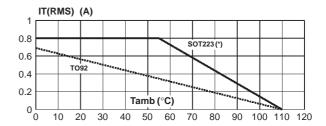
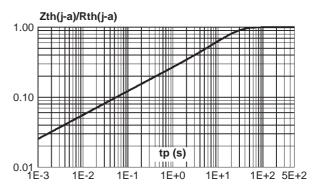
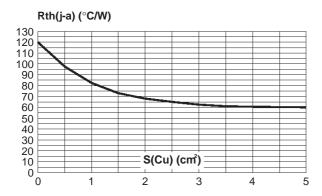


Fig 9-2: Relative variation of the junction to ambient thermal impedance versus conducting pulse duration for the TO92.

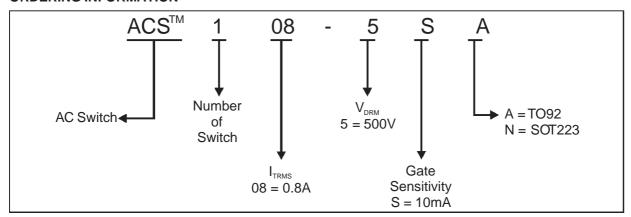


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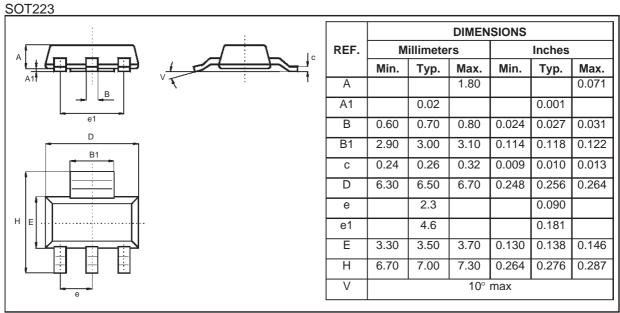
Fig. 10: SOT223 thermal resistance junction to ambient versus copper surface under tab (Epoxy printed circuit board FR4, copper thickness: $35\mu m$)



ORDERING INFORMATION

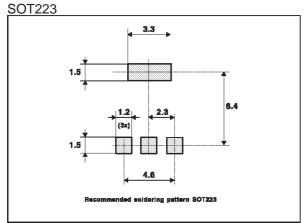


PACKAGE MECHANICAL DATA



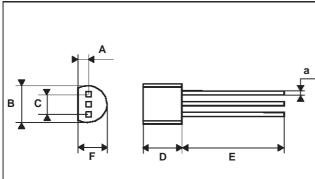
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PACKAGE MECHANICAL DATA



PACKAGE MECHANICAL DATA

TO92 Plastic



	DIMENSIONS						
REF.	Millimeters			Inches			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
Α		1.35			0.053		
В			4.70			0.185	
С		2.54			0.100		
D	4.40			0.173			
Е	12.70			0.500			
F			3.70			0.146	
а			0.45			0.017	

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
ACS108-5SA	ACS08/5S	TO92	0.2g	2500	Bulk
ACS108-5SN	ACS/085S	SOT223	0.123g	1000	Tape & reel

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